

# ZXTP25040DZ

## 40V PNP medium power transistor in SOT89

### Summary

$BV_{CEO} > -40V$

$BV_{ECO} > -3V$

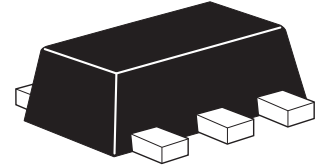
$I_{C(cont)} = -3.5A$

$R_{CE(sat)} = 55m\Omega$

$V_{CE(sat)} < -90mV @ 1A$

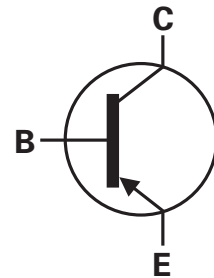
$P_D = 2.4W$

Complementary part number ZXTN25040DZ



### Description

Advanced process capability and package design have been used to maximize the power handling and performance of this small outline transistor. The compact size and ratings of this device make it ideally suited to applications where space is at a premium.

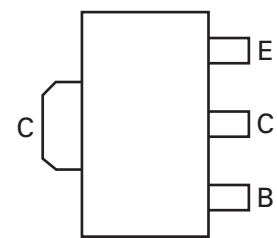


### Features

- High power dissipation SOT89 package
- High peak current
- Low saturation voltage
- 3V reverse blocking voltage

### Applications

- MOSFET and IGBT gate driving
- DC - DC converters
- Motor drive
- High side driver



Pinout - top view

### Ordering information

Device	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTP25040DZTA	7	12	1000

### Device marking

- 1L6

# ZXTP25040DZ

## Absolute maximum ratings

Parameter	Symbol	Limit	Unit
Collector-Base voltage	$V_{CBO}$	-45	V
Collector-Emitter voltage (forward blocking)	$V_{CEO}$	-40	V
Emitter-Collector voltage (reverse blocking)	$V_{ECO}$	-3	V
Emitter-Base voltage	$V_{EBO}$	-7	V
Continuous Collector current <sup>(c)</sup>	$I_C$	-3	A
Base current	$I_B$	-1	A
Peak pulse current	$I_{CM}$	-9	A
Power dissipation at $T_A = 25^\circ\text{C}^{(a)}$	$P_D$	1.1	W
Linear derating factor		8.8	mW/°C
Power dissipation at $T_A = 25^\circ\text{C}^{(b)}$	$P_D$	1.8	W
Linear derating factor		14.4	mW/°C
Power dissipation at $T_A = 25^\circ\text{C}^{(c)}$	$P_D$	2.4	W
Linear derating factor		19.2	mW/°C
Power dissipation at $T_A = 25^\circ\text{C}^{(d)}$	$P_D$	4.46	W
Linear derating factor		35.7	mW/°C
Power dissipation at $T_C = 25^\circ\text{C}^{(e)}$	$P_D$	15.7	W
Linear derating factor		126	mW/°C
Operating and storage temperature range	$T_j, T_{stg}$	-55 to 150	°C

## Thermal resistance

Parameter	Symbol	Limit	Unit
Junction to ambient <sup>(a)</sup>	$R_{\theta JA}$	117	°C/W
Junction to ambient <sup>(b)</sup>	$R_{\theta JA}$	68	°C/W
Junction to ambient <sup>(c)</sup>	$R_{\theta JA}$	51	°C/W
Junction to ambient <sup>(d)</sup>	$R_{\theta JA}$	28	°C/W
Junction to case <sup>(e)</sup>	$R_{\theta JC}$	7.95	°C/W

### NOTES:

(a) For a device surface mounted on 15mm x 15mm x 0.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.

(b) Mounted on 25mm x 25mm x 0.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.

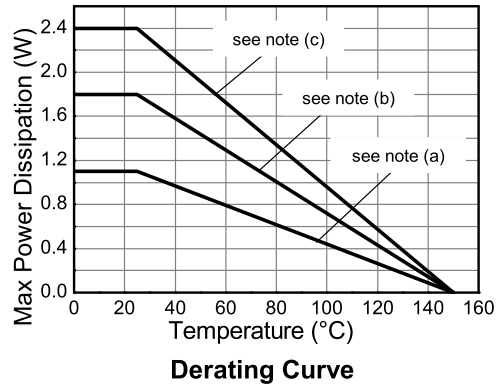
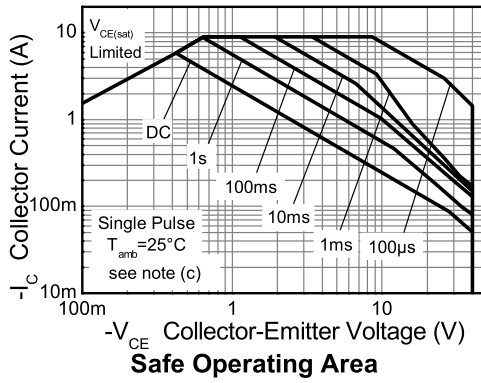
(c) Mounted on 50mm x 50mm x 0.6mm FR4 PCB with high coverage of single sided 2oz copper, in still air conditions.

(d) As (c) above measured at  $t < 5$  seconds.

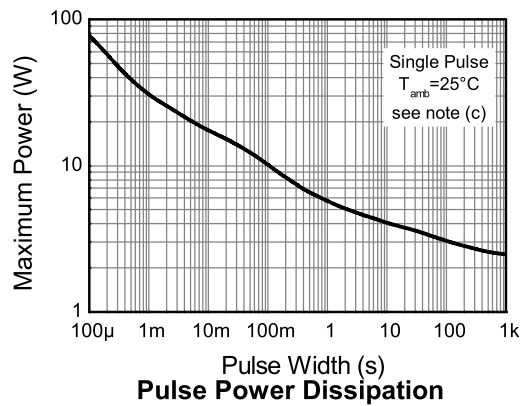
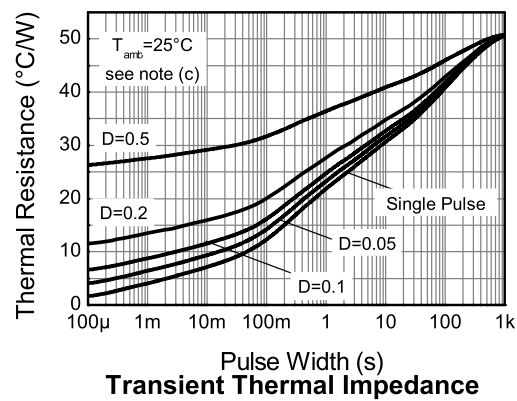
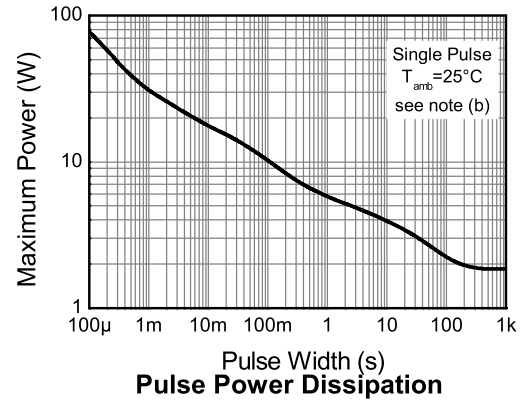
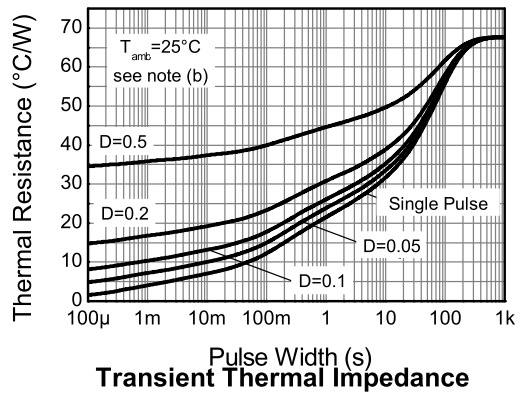
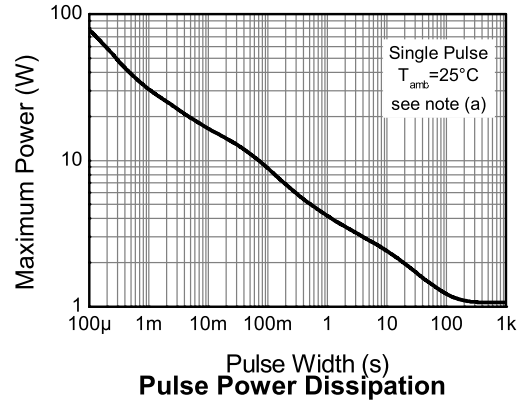
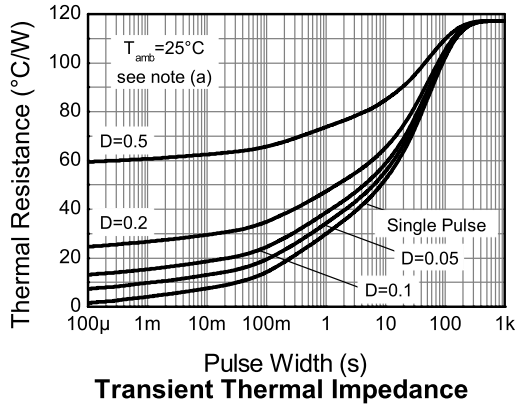
(e) Junction to case (collector tab). Typical

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## Thermal characteristics



## Thermal characteristics



# ZXTP25040DZ

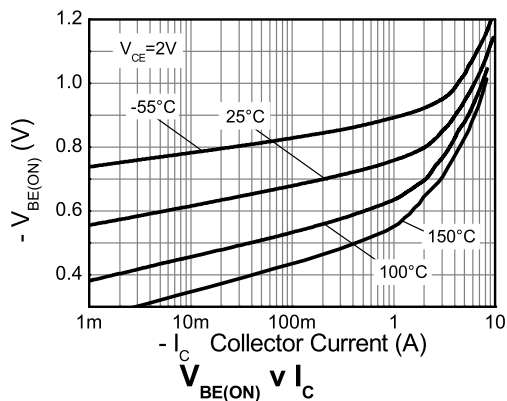
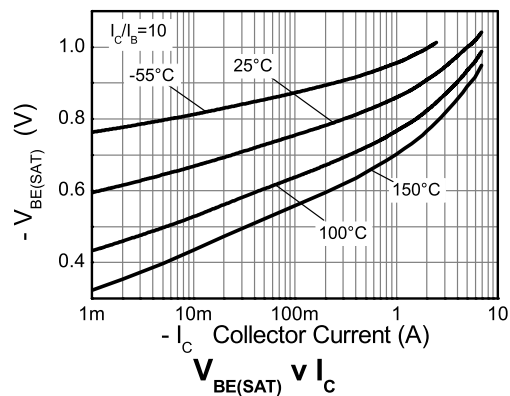
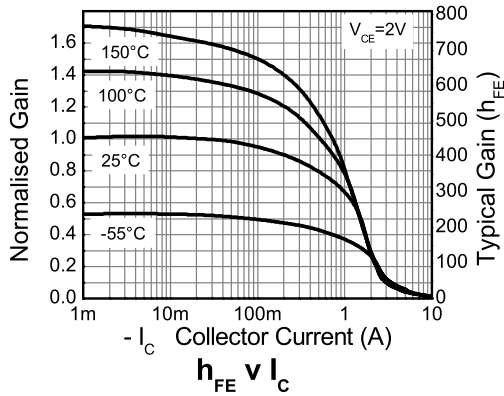
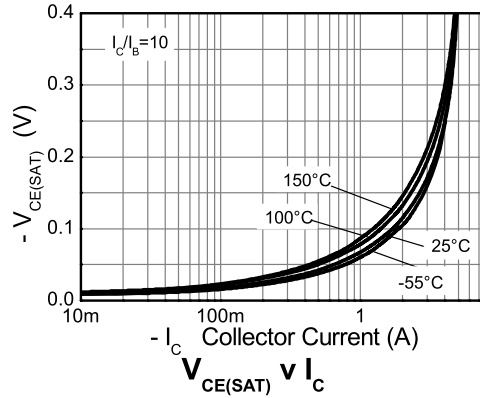
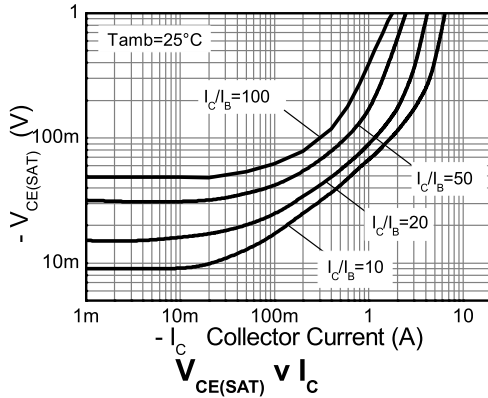
## Electrical characteristics (at $T_{amb} = 25^{\circ}\text{C}$ unless otherwise stated)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-Base breakdown voltage	$BV_{CBO}$	-45	-75		V	$I_C = -100\mu\text{A}$
Collector-Emitter breakdown voltage (base open)	$BV_{CEO}$	-40	-65		V	$I_C = -10\text{mA}^{(*)}$
Emitter-Collector breakdown voltage (reverse blocking)	$BV_{ECO}$	-3	-8.7		V	$I_E = -100\mu\text{A}$
Emitter-Base breakdown voltage	$BV_{EBO}$	-7	-8.2		V	$I_E = -100\mu\text{A}$
Collector cut-off current	$I_{CBO}$		<-1	-50 -0.5	nA $\mu\text{A}$	$V_{CB} = -45\text{V}$ $V_{CB} = -45\text{V}, T_{amb} = 100^{\circ}\text{C}$
Emitter cut-off current	$I_{EBO}$		<-1	-50	nA	$V_{EB} = -5.6\text{V}$
Collector-Emitter saturation voltage	$V_{CE(sat)}$		-170 -70 -215	-265 -90 -350	mV mV mV	$I_C = -1\text{A}, I_B = -20\text{mA}^{(*)}$ $I_C = -1\text{A}, I_B = -100\text{mA}^{(*)}$ $I_C = -3.5\text{A}, I_B = -350\text{mA}^{(*)}$
Base-Emitter saturation voltage	$V_{BE(sat)}$		-970	-1050	mV	$I_C = -3.5\text{A}, I_B = -350\text{mA}^{(*)}$
Base-emitter turn-on voltage	$V_{BE(on)}$		-870	-950	mV	$I_C = -3.5\text{A}, V_{CE} = -2\text{V}^{(*)}$
Static forward current transfer ratio	$h_{FE}$	300 200 20	450 300 50	900		$I_C = -10\text{mA}, V_{CE} = -2\text{V}^{(*)}$ $I_C = -1\text{A}, V_{CE} = -2\text{V}^{(*)}$ $I_C = -3.5\text{A}, V_{CE} = -2\text{V}^{(*)}$
Transition frequency	$f_T$		270		MHz	$I_C = -50\text{mA}, V_{CE} = -10\text{V}$ $f = 100\text{MHz}$
Input capacitance	$C_{ibo}$		142		pF	$V_{EB} = -0.5\text{V}, f = 1\text{MHz}^{(*)}$
Output capacitance	$C_{obo}$		17.4		pF	$V_{CB} = -10\text{V}, f = 1\text{MHz}^{(*)}$
Turn-on time	$t_{(on)}$		75.5		ns	$V_{CC} = -15\text{V}, I_C = -750\text{mA},$
Turn-off time	$t_{(off)}$		320		ns	$I_{B1} = -I_{B2} = -15\text{mA},$

### NOTES:

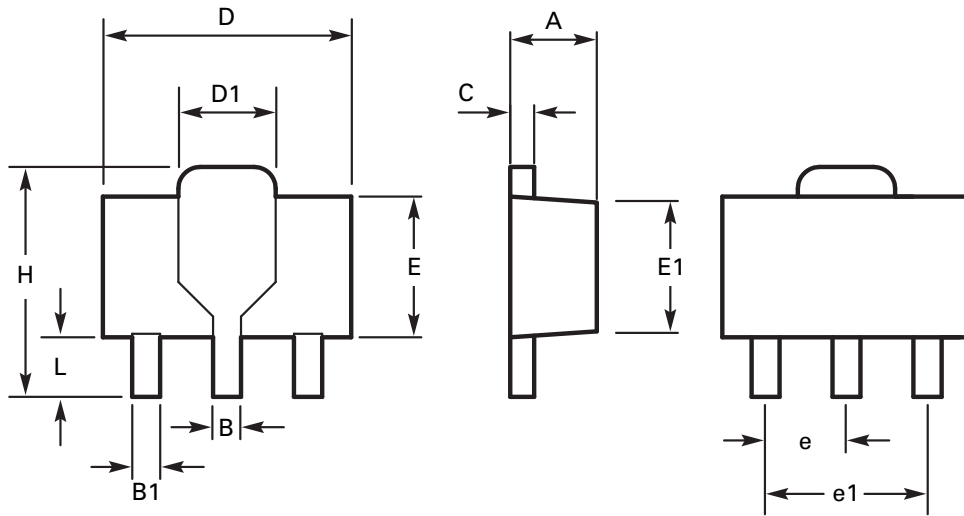
(\*) Measured under pulsed conditions. Pulse width  $\leq 300\mu\text{s}$ ; duty cycle  $\leq 2\%$ .

## Typical characteristics



# ZXTP25040DZ

## Package outline - SOT89



DIM	Millimeters		Inches		DIM	Millimeters		Inches	
	Min	Max	Min	Max		Min	Max	Min	Max
A	1.40	1.60	0.550	0.630	E	2.29	2.60	0.090	0.102
B	0.44	0.56	0.017	0.022	E1	2.13	2.29	0.084	0.090
B1	0.36	0.48	0.014	0.019	e	1.50 BSC		0.059 BSC	
C	0.35	0.44	0.014	0.017	e1	3.00 BSC		0.118 BSC	
D	4.40	4.60	0.173	0.181	H	3.94	4.25	0.155	0.167
D1	1.52	1.83	0.064	0.072	L	0.89	1.20	0.035	0.047

**Note:** Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

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Europe	Americas	Asia Pacific	Corporate Headquarters
Zetex GmbH Kustermann-park Balanstraße 59 D-81541 München Germany Telephone: (49) 89 45 49 49 0 Fax: (49) 89 45 49 49 49 europe.sales@zetex.com	Zetex Inc 700 Veterans Memorial Highway Hauppauge, NY 11788 USA Telephone: (1) 631 360 2222 Fax: (1) 631 360 8222 usa.sales@zetex.com	Zetex (Asia Ltd) 3701-04 Metroplaza Tower 1 Hing Fong Road, Kwai Fong Hong Kong Telephone: (852) 26100 611 Fax: (852) 24250 494 asia.sales@zetex.com	Zetex Semiconductors plc Zetex Technology Park, Chadderton Oldham, OL9 9LL United Kingdom Telephone: (44) 161 622 4444 Fax: (44) 161 622 4446 hq@zetex.com

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**Телефон:** 8 (812) 309 58 32 (многоканальный)

**Факс:** 8 (812) 320-02-42

**Электронная почта:** [org@eplast1.ru](mailto:org@eplast1.ru)

**Адрес:** 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.